
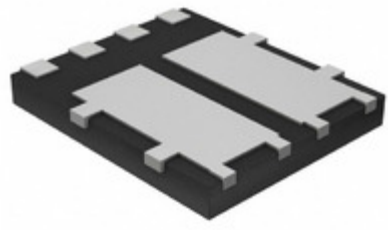
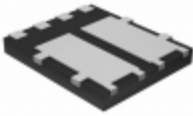
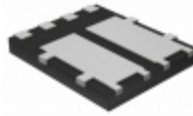
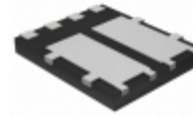
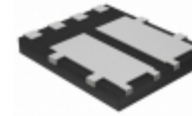
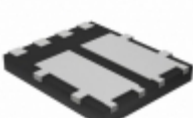
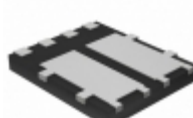
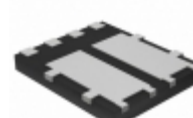
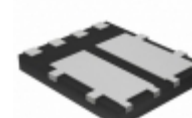
	<h2 style="color: red;">NVMFD5877NLT3G</h2>
	<p>Hersteller-Teilenummer: NVMFD5877NLT3G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET 2N-CH 60V 6A 8SOIC</p> <hr/> <p>Datenblätter:  NVMFD5877NLT3G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 835 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFD5877NLT3G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 60V 6A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	835 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3.2W
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-DFN (5x6)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	39 mOhm @ 7.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	540pF @ 25V
Verpackung	Tape & Reel (TR)



NVMFD5877NLT3G ist neu im Original, Suche NVMFD5877NLT3G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVMFD5877NLT3G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVMFD5877NLT3G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVMFD5875NLWFT3G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p>NVMFD5875NLT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p>NVMFD5C446NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 145A SO8FL</p>	 <p>NVMFD5877NLT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 6A 8SOIC</p>
 <p>NVMFD5875NLT3G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p>NVMFD5877NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 6A SO8FL</p>	 <p>NVMFD5C446NT1G AMI Semiconductor / ON Semiconductor 40V 2.9 MOHM T8 SO8FL DUA</p>	 <p>NVMFD5877NLWFT3G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 6A SO8FL</p>

heiße Teile

Mehr

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 BUK661R9-40C	 CDSOT23-T15C	 CL03C6R8CA3GNNC	 CPT300100	 DS1135LU-15+TR
 ELM13407CA-S	 GRM0336T1E8R1DD01D	 HA1209-AD0BLAG	 HAT2096H-EL-E	 HI1005-1C39NJMT
 IP-J6Z-CZ	 IS62WV51216BLL-55TLI	 ISL6420AIRZ-TK	 IXGH60N30C3	 KA1M0265R
 LC4512B-35FT256C	 MAX13046EELT+	 MPC860PZQ80D4	 NVMD3P03	 NVMD3P03R2G
 NVMD4N03	 NVMD6N04	 NVMFD5853NLT1G	 NVMFD5877NLWFT1G	 NVMFS4C01NWFT1G
 NVMFS4C05N	 NVMFS5113PLT1G	 NVMFS5830NLWFT1G	 NVMFS5885NLT3G	 NVMFS5C450NT1G
 NVMFS5C456NLT1G	 NVMFS5C468NLT1G	 PC9JB12DW	 PSND200E/06	 PT7A7513WE
 QM100DY-HE	 SA130CA-E3/73	 SAFC868P-1SRBA	 SMBJ150A	 SN74ALS576BNSR
 STBP110GTDJ6F	 SWI1008T68NJ	 T178F04TMC	 UPG153TB	 WS128JOPBFW01

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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